

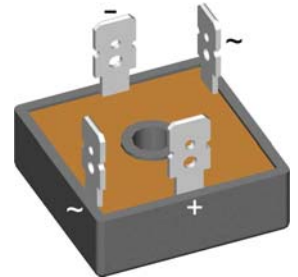
# Standard Rectifier Module

| 1~<br>Rectifier           |
|---------------------------|
| $V_{RRM} = 1200\text{ V}$ |
| $I_{DAV} = 18\text{ A}$   |
| $I_{FSM} = 550\text{ A}$  |

## 1~ Rectifier Bridge

Part number

**VBO36-12NO8**



 E72873



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

### Applications:

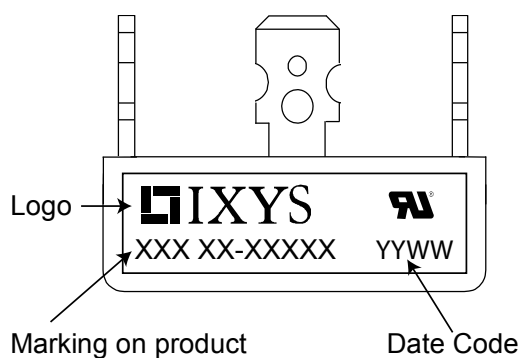
- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: FO-B

- Industry standard outline
- RoHS compliant
- ¼" fast-on terminals
- Easy to mount with one screw

| Rectifier  |                                              |                                                     |                                | Ratings                        |      |      |                   |
|------------|----------------------------------------------|-----------------------------------------------------|--------------------------------|--------------------------------|------|------|-------------------|
| Symbol     | Definition                                   | Conditions                                          |                                | min.                           | typ. | max. | Unit              |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                       |                                |                                |      | 1300 | V                 |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                       |                                |                                |      | 1200 | V                 |
| $I_R$      | reverse current                              | $V_R = 1200\text{ V}$                               | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 40   | $\mu\text{A}$     |
|            |                                              | $V_R = 1200\text{ V}$                               | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 1.5  | mA                |
| $V_F$      | forward voltage drop                         | $I_F = 15\text{ A}$                                 | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1.04 | V                 |
|            |                                              | $I_F = 30\text{ A}$                                 |                                |                                |      | 1.14 | V                 |
|            |                                              | $I_F = 15\text{ A}$                                 | $T_{VJ} = 125^{\circ}\text{C}$ |                                |      | 0.93 | V                 |
|            |                                              | $I_F = 30\text{ A}$                                 |                                |                                |      | 1.06 | V                 |
| $I_{DAV}$  | bridge output current                        | $T_C = 85^{\circ}\text{C}$<br>rectangular $d = 0.5$ | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 18   | A                 |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only                   |                                | $T_{VJ} = 150^{\circ}\text{C}$ |      | 0.76 | V                 |
| $r_F$      | slope resistance                             |                                                     |                                |                                |      | 9.1  | m $\Omega$        |
| $R_{thJC}$ | thermal resistance junction to case          |                                                     |                                |                                |      | 7    | K/W               |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                     |                                |                                | 1    |      | K/W               |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                          |                                |                                |      | 17   | W                 |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$    | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 550  | A                 |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$   | $V_R = 0\text{ V}$             |                                |      | 595  | A                 |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$    | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 470  | A                 |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$   | $V_R = 0\text{ V}$             |                                |      | 505  | A                 |
| $I^2t$     | value for fusing                             | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$    | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 1.52 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$   | $V_R = 0\text{ V}$             |                                |      | 1.48 | kA <sup>2</sup> s |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$    | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 1.11 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$   | $V_R = 0\text{ V}$             |                                |      | 1.06 | kA <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$              |                                | $T_{VJ} = 25^{\circ}\text{C}$  | 18   |      | pF                |

| Package FO-B         |                                                              |                      |                                         | Ratings |      |      |      |
|----------------------|--------------------------------------------------------------|----------------------|-----------------------------------------|---------|------|------|------|
| Symbol               | Definition                                                   | Conditions           |                                         | min.    | typ. | max. | Unit |
| I <sub>RMS</sub>     | RMS current                                                  | per terminal         |                                         |         |      | 100  | A    |
| T <sub>stg</sub>     | storage temperature                                          |                      |                                         | -40     |      | 125  | °C   |
| T <sub>VJ</sub>      | virtual junction temperature                                 |                      |                                         | -40     |      | 150  | °C   |
| Weight               |                                                              |                      |                                         |         | 19   |      | g    |
| M <sub>D</sub>       | mounting torque                                              |                      |                                         | 1.8     |      | 2.2  | Nm   |
| d <sub>Spp/App</sub> | creepage distance on surface   striking distance through air | terminal to terminal | 9.0                                     | 7.0     |      |      | mm   |
| d <sub>Spb/Apb</sub> |                                                              | terminal to backside | 10.0                                    | 10.0    |      |      | mm   |
| V <sub>ISOL</sub>    | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; I <sub>ISOL</sub> ≤ 1 mA | 3000    |      |      | V    |
|                      |                                                              | t = 1 minute         |                                         | 2500    |      |      | V    |



| Ordering | Part Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-------------|--------------------|---------------|----------|----------|
| Standard | VBO36-12NO8 | VBO36-12NO8        | Box           | 50       | 471984   |

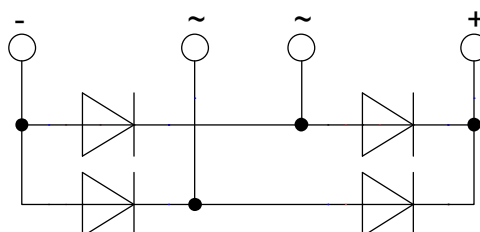
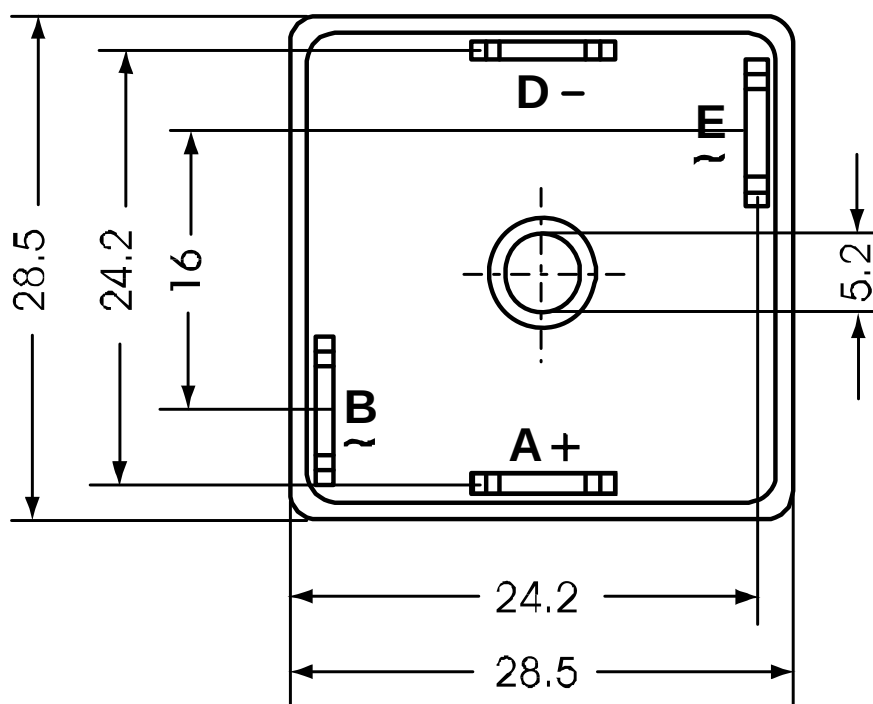
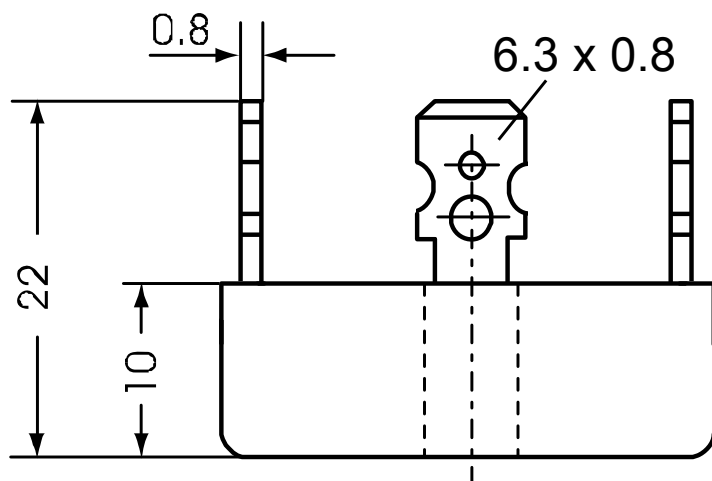
### Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 150^\circ\text{C}$

|             |                    |           |    |
|-------------|--------------------|-----------|----|
|             |                    | Rectifier |    |
| $V_{0\max}$ | threshold voltage  | 0.76      | V  |
| $R_{0\max}$ | slope resistance * | 7.9       | mΩ |

**Outlines FO-B**



## Rectifier

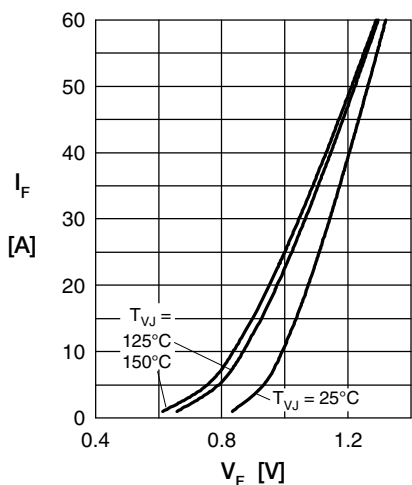


Fig. 1 Forward current vs. voltage drop per diode

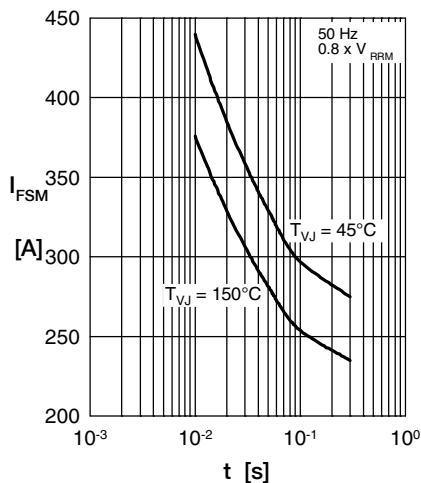


Fig. 2 Surge overload current vs. time per diode

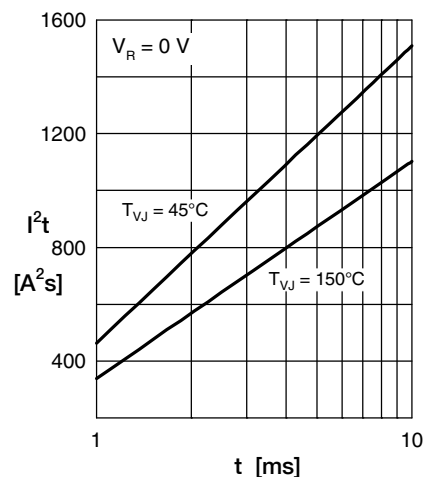


Fig. 3  $I^2t$  vs. time per diode

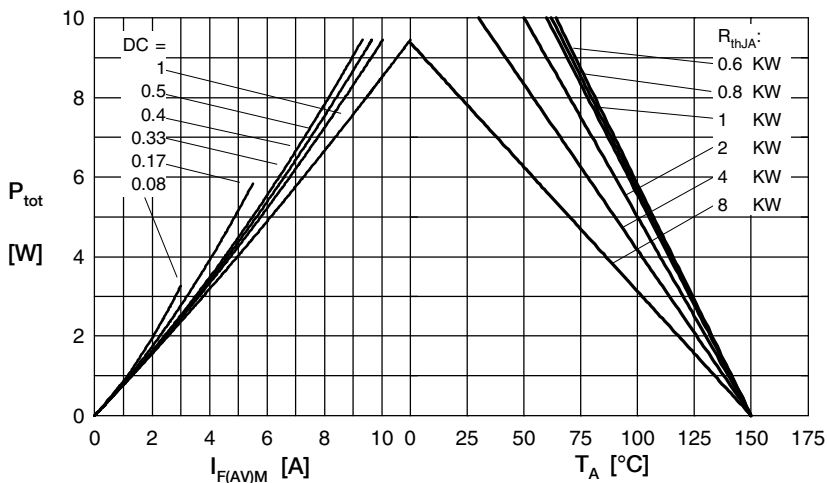


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

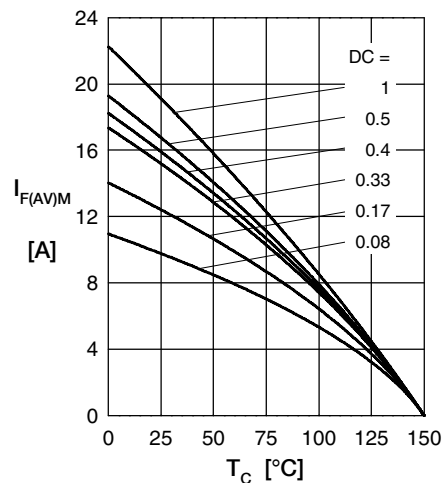


Fig. 5 Max. forward current vs. case temperature per diode

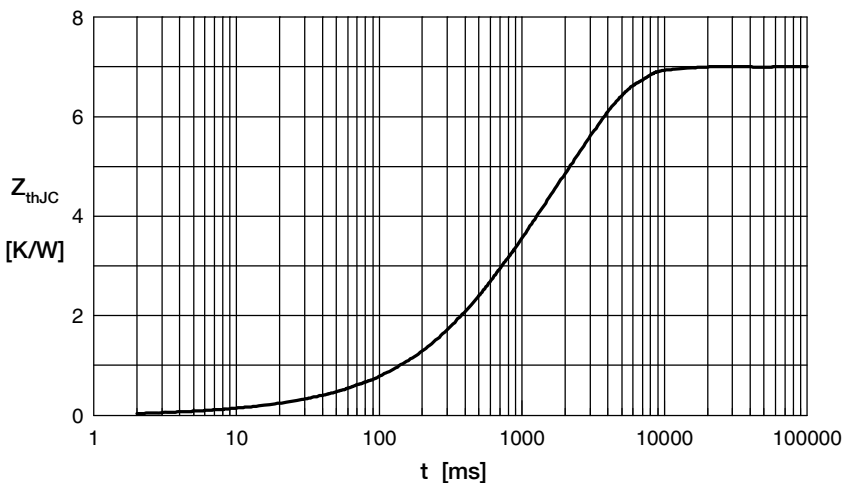


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

| i | $R_{th}$ (K/W) | $t_i$ (s) |
|---|----------------|-----------|
| 1 | 0.040          | 0.005     |
| 2 | 0.150          | 0.030     |
| 3 | 1.710          | 0.400     |
| 4 | 5.100          | 2.300     |